SANYO

Monolithic Digital IC

LB1205

unit

High-Voltage, High-Current Darlington Driver

Functions and Features

- . 4-unit, high-voltage (65V), high-current (1.5A) Darlington driver
- . PNP input type (Low active)
- . On-chip spark killer diodes
- . On-chip input protection diodes

NO.1831C

. Capable of being driven directly from 5V-operated CMOS, TTL

| Absolute Maximum Ratings at Ta | a=25 ⁰ C | | | unit |
|---------------------------------------|---------------------|----------------------|-----------------------------------|------|
| Maximum Supply Voltage | V _{DD} max | | 7.0 | V |
| | V _{CC} max | | 62 | v |
| Output Supply Voltage | Vomax | | 65 | v |
| Input Supply Voltage | V _{TN} max | V _{TN} ≧Gnd | $V_{DD} - 7.0$ to $V_{DD} + 10.0$ | V |
| Output Current | Iomax | 14 | 1.5 | A |
| Spark Killer Diode Forward Current | IFS | | 1.5 | A |
| Allowable Power Dissipation | Pdmax* | | #1.9 | W |
| Operating Temperature | Topr | • | -20 to +75 | ٥Ĉ |
| Storage Temperature | Tstg | | -55 to +150 | °Č |
| #Mounted on the | e recomme | nded printed | | Ŵ |

Allowable Operating Conditions at Ta=25°C

| Supply Voltage Range | | 0 to 7.0 V |
|---------------------------|--|-------------------------|
| Input "ON" Level Voltage | $V_{\rm TNon}$ $V_{\rm TN} \leq Gnd$, Io=1.0A $V_{\rm DD} = 7.0$ to | V _{DD} -2.6 V |
| Input "OFF" Level Voltage | $V_{\rm INOFF} Io^{2}30\mu A$ $V_{\rm DD}-0.3$ to | V _{DD} +10.0 V |
| | | |

| Electrical Characteristics at | Ta=25°C | , V _{DD} =5.0V | min | typ | max | unit | |
|---------------------------------------|--------------------|---|-----|-----|-----|------|--|
| Output Saturation Voltage | V _{osat1} | V _{IN} =V _{DD} -5.0V, Io=0.5A | | • - | 1.2 | v | |
| | V _{osat2} | ,Io=1.0A | | | 1.5 | V | |
| • • • • • | V _{osat3} | ",Io=1.5A | | | 2.0 | V | |
| Output Sustain Voltage | Vosus | Io=100mA | 65 | | | V | |
| Input Current | ITN | $V_{DD} = 7.0V, V_{IN} = V_{DD} - 7.0V$ | | | 1.0 | mA | |
| Spark Killer Diode Forward Voltage | VFs | I _{Fs} =1.5A | | | 3.0 | V | |
| Spark Killer Diode Reverse Current | I_{Rs} | V _{CC} =62V, Vo=0V | | | 30 | ۸ىر | |

Package Dimensions 3054A (unit : mm) ¹⁶



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